## NSN 5962-01-078-0474

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View Online at https://aerobasegroup.com/nsn/5962-01-078-0474
Body Length:
Between 0.750 inches and 0.785 inches
Body Width:
Between 0.285 inches and 0.291 inches
Body Height:
Between 0.120 inches and 0.185 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Wsd: aircraft, stratofortess b-52
Features Provided:
Hermetically sealed and monolithic and positive outputs and low power and schottky and w/open collector and programmable and
programmed and w/enable and w/disable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
26916-058-00182 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/o

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

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